IN THE CLAIMS:

The following is a list of all pending claims. Please revise the claims to read as follows:

- 1-31 cancelled.
- 32. (Currently Amended) The method of claim [[31]] <u>35</u> wherein said channel permits the removal of residual flux.
- 33. (Currently Amended). the method of claim [[31]] <u>35</u> wherein the chip carrier has a first coefficient of thermal expansion different from a coefficient of thermal expansion of the semiconductor device.
- 34. (Currently Amended). The method of claim [[31]] <u>35</u> wherein the chip carrier has a first coefficient of thermal expansion different from a coefficient of thermal expansion of the intermediate mounting substrate.
- 35. (Currently Amended) The method of claim 31 wherein A method of underfilling a gap between a multi-sided semiconductor device and a chip carrier on which it is mounted to encapsulate a plurality of electrical connections formed therebetween wherein said chip carrier is mounted on an intermediate mounting substrate and the intermediate mounting substrate is adapted for connection to a printed circuit board, comprising

forming a channel extending through said intermediate mounting substrate and said chip carrier to said gap; and

dispensing through said channel an under-fill material into said gap, said intermediate mounting substrate having a coefficient of thermal expansion different from a coefficient of thermal expansion of the chip carrier and smaller than a coefficient of thermal expansion of the printed circuit board.

1-NY/1868446.1 -2-